

PROCEEDINGS OF SPIE

# ***Laser Material Processing for Solar Energy Devices II***

**Edward W. Reutzel**  
*Editor*

**28–29 August 2013**  
**San Diego, California, United States**

*Sponsored and Published by*  
SPIE

**Volume 8826**

Proceedings of SPIE 0277-786X, V. 8826

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Laser Material Processing for Solar Energy Devices II, edited by Edward W. Reutzel,  
Proc. of SPIE Vol. 8826, 882601 · © 2013 SPIE · CCC code: 0277-786X/13/\$18 · doi: 10.1117/12.2045830

Proc. of SPIE Vol. 8826 882601-1

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Author(s), "Title of Paper," in *Laser Material Processing for Solar Energy Devices II*, edited by Edward W. Reutzel, Proceedings of SPIE Vol. 8826 (SPIE, Bellingham, WA, 2013) Article CID Number.

ISSN: 0277-786X

ISBN: 9780819496768

Published by

**SPIE**

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

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# Contents

v *Conference Committee*

## SESSION 1 DOPING AND CONTACTING

---

- 8826 03 **New laser-based approaches to improve the passivation and rear contact quality in high efficiency crystalline silicon solar cells (Invited Paper)** [8826-2]  
C. Molpeceres, Univ. Polit cnica de Madrid (Spain); M. Colina, Univ. Polit cnica de Catalunya (Spain); D. Mu oz-Martin, Univ. Polit cnica de Madrid (Spain); I. Mart n, P. Ortega, Univ. Polit cnica de Catalunya (Spain); I. S nchez, M. Morales, S. Lauzurica, J. J. Garc a-Ballesteros, Univ. Polit cnica de Madrid (Spain); C. Voz, G. L pez, A. B. Morales, R. Alcubilla, Univ. Polit cnica de Catalunya (Spain)
- 8826 04 **Investigation of metal contacts for silicon solar cells using laser processed 8 m thick Al foils** [8826-3]  
L. Wang, Univ. of Virginia (United States); D. E. Carlson, Carlson PV (United States); M. C. Gupta, Univ. of Virginia (United States)
- 8826 06 **Role of processing parameters on morphology, resistance and composition of laser fired contacts** [8826-5]  
A. Raghavan, T. A. Palmer, A. Domask, S. Mohny, E. W. Reutzler, T. DebRoy, The Pennsylvania State Univ. (United States)
- 8826 07 **Pulsed UV laser annealing of polycrystalline CdTe** [8826-6]  
B. J. Simonds, The Univ. of Utah (United States); V. Palekis, M. I. Khan, C. S. Ferekides, Univ. of South Florida (United States); M. A. Scarpulla, The Univ. of Utah (United States)

## SESSION 2 SPECIAL TOPICS

---

- 8826 09 **Comparison of picosecond laser sources for SiN<sub>x</sub> ablation with subsequent nickel silicide formation by excimer laser annealing (ELA) for high efficiency silicon solar cells** [8826-9]  
S. Gall, J. Vibert, M. Pirot, CEA, LITEN, Institut National de l'Energie Solaire (France); J.-F. Lerat, T. Emeraud, EXCICO Group NV (Belgium); N. Le Quang, EDF ENR PWT, Photowatt (France); A. Slaoui, Institut d'Electronique du Solide et des Syst mes (France); A. Bahouka, IREPA Laser (France)
- 8826 0A **Optimal irradiance for sintering of inkjet-printed Ag electrodes with a 532nm CW laser** [8826-10]  
Y. J. Moon, H. Kang, K. Kang, J. Y. Hwang, KITECH (Korea, Republic of); S. J. Moon, Hanyang Univ. (Korea, Republic of)

---

**SESSION 3 SURFACE MODIFICATION, SCRIBING, AND STRUCTURING I**

---

- 8826 0C **Study of the laser scribing of molybdenum thin films fabricated using different deposition techniques** [8826-12]  
E. Schneller, N. G. Dhere, J. Shimada, Florida Solar Energy Ctr. (United States); A. Kar, CREOL, The College of Optics and Photonics, Univ. of Central Florida (United States)

---

**SESSION 4 SURFACE MODIFICATION, SCRIBING, AND STRUCTURING II**

---

- 8826 0E **Laser crystallization and localized growth of nanomaterials for solar applications (Invited Paper)** [8826-15]  
J. B. In, S.-G. Ryu, D. Lee, S. Ahn, A. C. Zheng, Univ. of California, Berkeley (United States); D. J.-S. Hwang, Stony Brook Univ. (United States); C. P. Grigoropoulos, Univ. of California, Berkeley (United States)
- 8826 0F **Beam shaping imaging system for laser microprocessing with scanning optics** [8826-16]  
A. Laskin, AdlOptica GmbH (Germany); N. Šiaulys, G. Šlekys, Altechna/WOP (Lithuania); V. Laskin, AdlOptica GmbH (Germany)
- 8826 0G **Laser drilling up to 15,000 holes/sec in silicon wafer for PV solar cells** [8826-17]  
R. Patwa, H. Herfurth, Fraunhofer USA Inc. (United States); G. Mueller, K. Bui, SolarWorld Industries America Inc. (United States)
- 8826 0I **Optical and electrical properties of SnO<sub>2</sub> thin films after ultra-short pulsed laser annealing** [8826-19]  
D. Scorticati, Univ. Twente (Netherlands); A. Illiberi, TNO (Netherlands); G. R. B. E. Römer, T. Bor, W. Ogieglo, M. Klein Gunnewiek, A. Lenkferink, C. Otto, Univ. Twente (Netherlands); J. Z. P. Skolski, Univ. Twente (Netherlands) and M2i (Netherlands); F. Grob, TNO (Netherlands); D. F. de Lange, Univ. Autónoma de San Luis Potosí (Mexico); A. J. Huis in 't Veld, Univ. Twente (Netherlands) and TNO (Netherlands)

*Author Index*

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- 2 Special Topics  
**Edward W. Reutzel**, Pennsylvania State University (United States)
- 3 Surface Modification, Scribing, and Structuring I  
**Aravinda Kar**, CREOL, The College of Optics and Photonics, University of Central Florida (United States)
- 4 Surface Modification, Scribing, and Structuring II  
**David J.-S. Hwang**, Stony Brook University (United States)

